

ES3A THRU ES3M

SUPER FAST SURFACE MOUNT RECTIFIERS

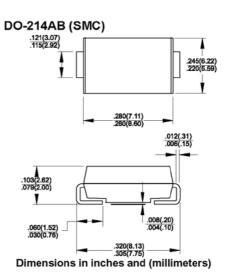
Reverse Voltage - 50 to 1000 Volts Forward Current - 3.0 Amperes

Features

- Glass passivated junction chip
- For surface mounted application
- ◆ Low profile package
- Built-in strain relief
- Ideal for automated placement
- ◆ Easy pick and place
- Superfast recovery time for high efficiency
- Glass passivated chip junction
- High temperature soldering: 250°C/10 seconds at terminals
- Plastic material used carries Underwriters Laboratory Classification 94V-O

Mechanical Data

- ◆ Cases: Molded plastic
- ◆ Terminals: Solder plated
- Polarity: Indicated by cathode band
- ♦ Weight: 0.007 ounce, 0.21 gram



Maximum Ratings and Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%

| Parameter | Symbols | ES 3A | ES 3B | ES 3C | ES 3D | ES 3F | ES 3G | ES 3J | ES 3K | ES 3M | Units |
|--|--------------------------------------|-------------|----------|----------|----------|----------|----------|----------|----------|----------|----------|
| Maximum repetitive peak reverse voltage | V _{RRM} | 50 | 100 | 150 | 200 | 300 | 400 | 600 | 800 | 1000 | Volts |
| Maximum RMS voltage | V _{RMS} | 35 | 70 | 105 | 140 | 210 | 280 | 420 | 560 | 700 | Volts |
| Maximum DC blocking voltage | V _{DC} | 50 | 100 | 150 | 200 | 300 | 400 | 600 | 800 | 1000 | Volts |
| Maximum average forward rectified current See Fig. 1 | I _(AV) | 3.0 | | | | | | | | Amps | |
| Peak forward surge current, 8.3ms single half sine-wave superimposed on rated load (JEDEC Method) @T _L =100°C | I _{FSM} | 100.0 | | | | | | | | | Amps |
| Maximum instantaneous forward voltage @ 3.0A | V _F | 0.95 | | | | 1.3 | | 1.7 | | Volts | |
| Maximum DC reverse current@ $T_A = 25^{\circ}C$ at rated DC blocking voltage@ $T_A = 100^{\circ}C$ | I _R | 10.0 500 | | | | | | | | | uA uA |
| Maximum reverse recovery time (Note 1) | t _{rr} | 35 | | | | | | | | | nS |
| Typical junction capacitance (Note 2) | C | 50 40 | | | | | | | pF | | |
| Typical thermal resistance (Note 3) | R _{eja} R _{ejl} | 47 12 | | | | | | | | | °C/W |
| Operating junction temperature range | Tj | -55 to +150 | | | | | | | | | °C |
| Storage temperature range | T _{stg} | -55 to +150 | | | | | | | | | °C |

Reverse Recovery Test Conditions: I_F=0.5A, I_R=1.0A, I_{RR}=0.25

2. Measured at 1 MHz and Applied V_p=4.0 Volts

3. Units Mounted on P.C.B. with 0.31 x 0.31" (8.0

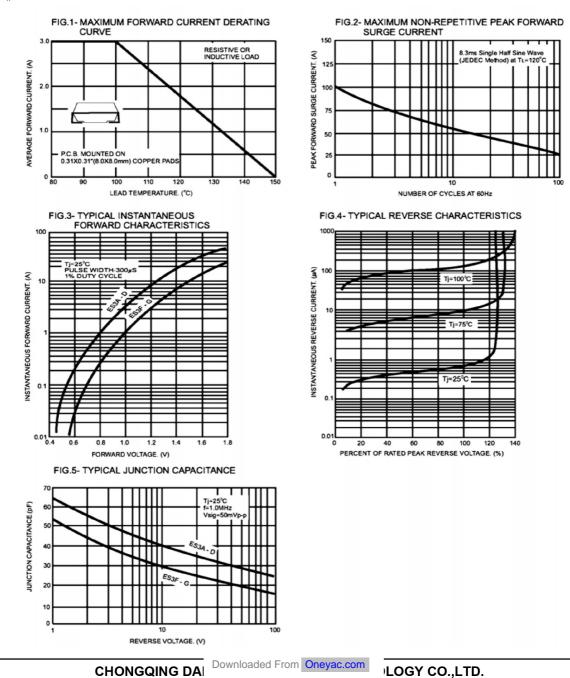
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RATINGS AND CHARACTERISTIC CURVES ES3A THRU ES3M

(T_A = 25°C unless otherwise noted)



单击下面可查看定价,库存,交付和生命周期等信息

>>RCD(达标电子)